



**DACO SEMICONDUCTOR CO., LTD.**

**MBRA60030CTL**

## LOW VF SCHOTTKY DIODE MODULE TYPE 600A

### Features

High Surge Capability

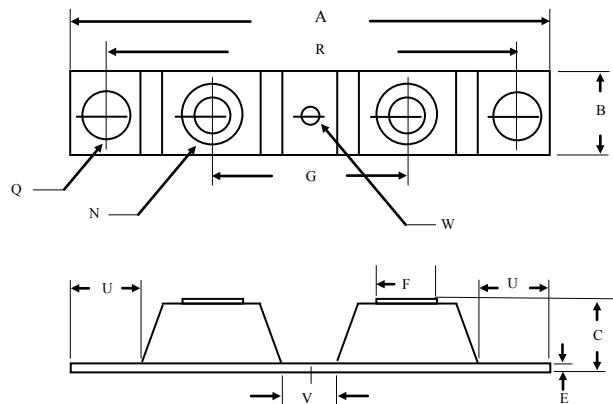
**600Amp Rectifier  
30 Volts**

### Maximum Ratings

Operating Temperature: -40 °C to +100 °C  
Storage Temperature: -40 °C to +150 °C

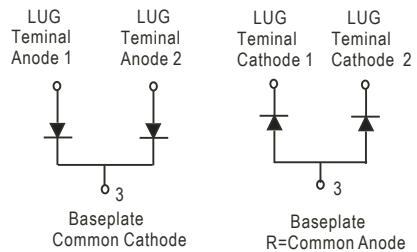
Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBRA60030CTL	30V	21V	30V

### HEAVY TWIN TOWER



### Electrical Characteristics @ 25 °C Unless Otherwise Specified

Average Forward Current (Per pkg)	I <sub>F(AV)</sub>	600A	TC=100°C
Peak Forward Surge Current (Per leg)	I <sub>FSM</sub>	4000A	8.3ms, half sine
Maximum Instantaneous Forward Voltage (Per leg)	V <sub>F</sub>	0.58V	I <sub>FM</sub> =300A; TJ=25 °C
Maximum Instantaneous Reverse Current At Rated DC Blocking Voltage (Per leg)	I <sub>R</sub>	3.0 mA 250mA	TJ = 25 °C TJ = 100 °C
Maximum Thermal Resistance Junction To Case (Per leg)	R <sub>θ j c</sub>	0.28 °C/W	



DIM	Inches		Millimeters	
	Min	Max	Min	Max
A	----	3.64	----	92.3
B	1.06	1.067	26.9	27.1
C	----	0.740	----	18.8
E	0.134	0.14	3.4	3.55
F	0.520	0.527	13.2	13.4
G	1.49	BSC	38.0	BSC
N	1/4-20 UNC FULL			
Q	0.275	0.290	6.99	7.37
R	3.150	BSC	80.01	BSC
U	0.512	----	13.0	----
V	0.449	0.472	11.4	12.0
W	0.180	0.195	4.57	4.95

#### NOTE :

- (1) Pulse Test: Pulse Width 300  $\mu$  sec. Duty Cycle < 2%

